

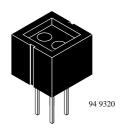
Reflective Optical Sensor with Transistor Output

Description

The CNY70 has a compact construction where the emitting light source and the detector are arranged in the same direction to sense the presence of an object by using the reflective IR beam from the object. The operating wavelength is 950 nm. The detector consists of a phototransistor.

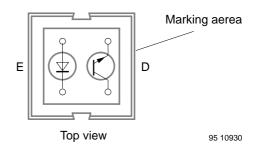
Applications

• Optoelectronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (optoelectronic encoder assemblies transmission sensing).



Features

- Compact construction in center-to-center spacing
- No setting required
- High signal output
- Low temperature coefficient
- Detector provided with optical filter
- Current Transfer Ratio (CTR) of typical 5%



Order Instruction

Ordering Code	Sensing Distance	Remarks
CNY70	0.3 mm	

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Absolute Maximum Ratings

Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_{R}	5	V
Forward current		l _F	50	mA
Forward surge current	t _p ≤ 10 μs	I _{FSM}	3	Α
Power dissipation	T _{amb} ≤ 25 °C	P_V	100	mW
Junction temperature		T _i	100	°C

Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V _{CEO}	32	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		I _C	50	mA
Power dissipation	T _{amb} ≤ 25 °C	P_V	100	mW
Junction temperature		T _i	100	°C

Coupler

Parameter	Test Conditions	Symbol	Value	Unit
Total power dissipation	T _{amb} ≤ 25 °C	P_{tot}	200	mW
Ambient temperature range		T _{amb}	-55 to +85	Ĵ
Storage temperature range		T _{stg}	-55 to +100	°C
Soldering temperature	2 mm from case, t ≤ 5 s	T _{sd}	260	°C



Electrical Characteristics $(T_{amb} = 25^{\circ}C)$

Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 50 mA	V_{F}		1.25	1.6	V

Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector emitter voltage	I _C = 1 mA	V_{CEO}	32			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	5			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_f = 0, E = 0$	I _{CEO}			200	nA

Coupler

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector current	$V_{CE} = 5 \text{ V}, I_{F} = 20 \text{ mA},$ d = 0.3 mm (figure 1)	I _C ¹⁾	0.3	1.0		mA
Cross talk current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}$ (figure 1)	I _{CX} ²⁾			600	nA
Collector emitter satu- ration voltage	$I_F = 20 \text{ mA}, I_C = 0.1 \text{ mA},$ d = 0.3 mm (figure 1)	V _{CEsat} 1)			0.3	V
1) Measured with the 'Kodak neutral test card', white side with 90% diffuse reflectance						

2) Measured without reflecting medium

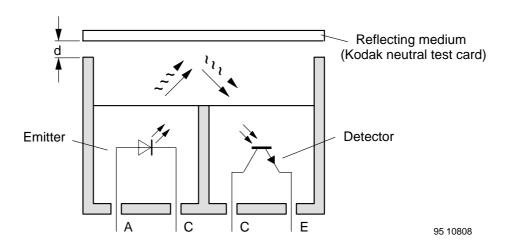


Figure 1. Test circuit

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Typical Characteristics (T_{amb} = 25°C, unless otherwise specified)

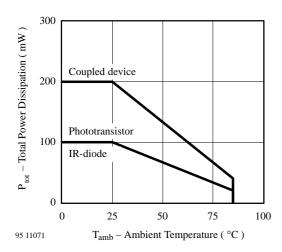


Figure 2. Total Power Dissipation vs. Ambient Temperature

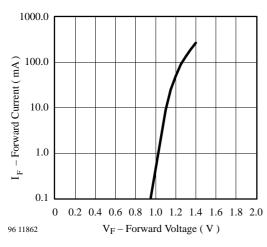


Figure 3. Forward Current vs. Forward Voltage

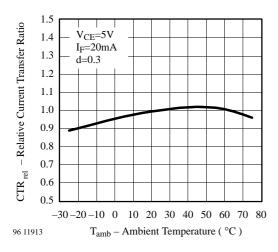


Figure 4. Relative Current Transfer Ratio vs.
Ambient Temperature

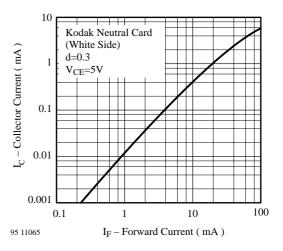


Figure 5. Collector Current vs. Forward Current

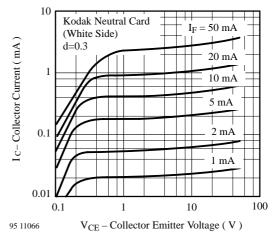


Figure 6. Collector Current vs. Collector Emitter Voltage

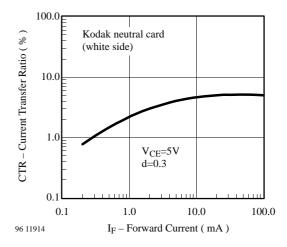


Figure 7. Current Transfer Ratio vs. Forward Current



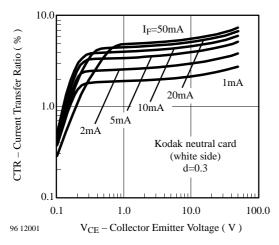


Figure 8. Current Transfer Ratio vs. Collector Emitter Voltage

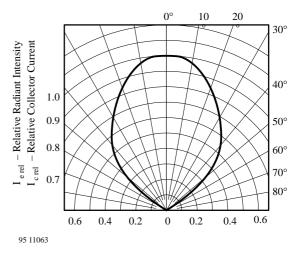


Figure 10. Relative Radiant Intensity/Collector Current vs.
Displacement

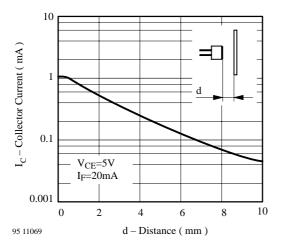


Figure 9. Collector Current vs. Distance

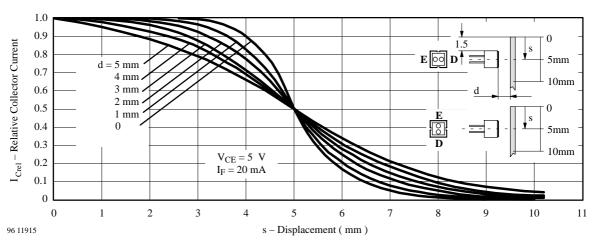
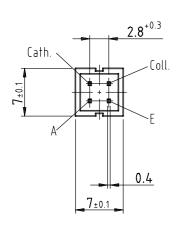


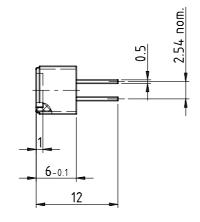
Figure 11. Relative Collector Current vs. Displacement

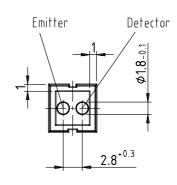
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Dimensions of CNY70 in mm







weight: ca. 0.70g

technical drawings according to DIN specifications

Drawing-No.: 6.544-5062.01-4

Issue: 4; 24.03.00

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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